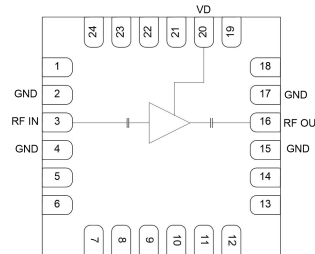


## GaAs MMIC Low Noise Amplifier Chip, 2 - 8 GHz

### Performance characteristics

- Frequency range: 2 - 8 GHz
- Small Signal Gain: 14 dB
- Noise figure: 2.6dB typ
- P -1 dB: 16.5dBm
- Power supply: + 5V /55mA
- 50Ohm input / output
- Chip size: QFN 4X4

### Functional Block Diagram



### Product Introduction

GLA-0208A-CQ4 is a broadband low noise amplifier chip with a frequency range of 2GHz~8GHz, a small signal gain of 14dB, and an in-band noise factor of 2.6dB . GLA -0208A-CQ4 is powered by a single +5V power supply. The amplifier uses a 4X4mm surface-mount leadless ceramic tube shell to achieve airtight packaging. The surface of the pin pad is gold-plated and is suitable for reflow soldering installation.

### Use restriction parameter <sup>1</sup>

Maximum drain voltage	+7V
Maximum input power	+20dBm
Operating temperature	-55 ~ +85°C
storage temperature	-65 ~ +150°C

【1】 Exceeding any of these maximum limits may cause permanent damage.

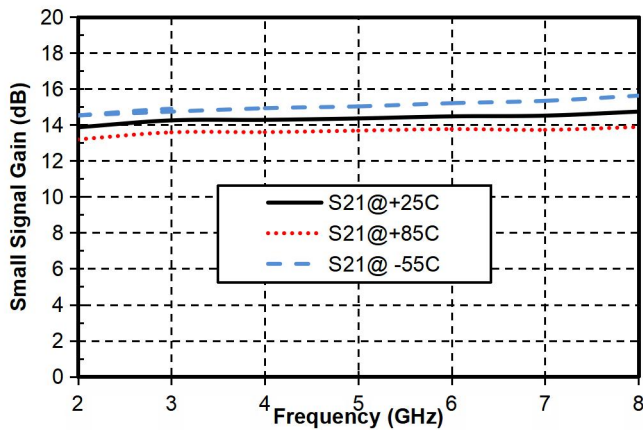
### Electrical performance parameters (TA = +25°C, Vd = +5V)

Index	Minimum	Typical Value	Maximum	Unit
Frequency Range	2-8			G Hz
Small Signal Gain	-	14	-	dB
Gain Flatness	-	± 0.5	-	dB
Noise Figure	-	2.6	-	dB
P -1 dB	-	16.5	-	dBm
Psat	-	17.5	-	dBm
Input return loss	-	16	-	dB
Output return loss	-	13	-	dB
Quiescent Current	-	55	-	mA

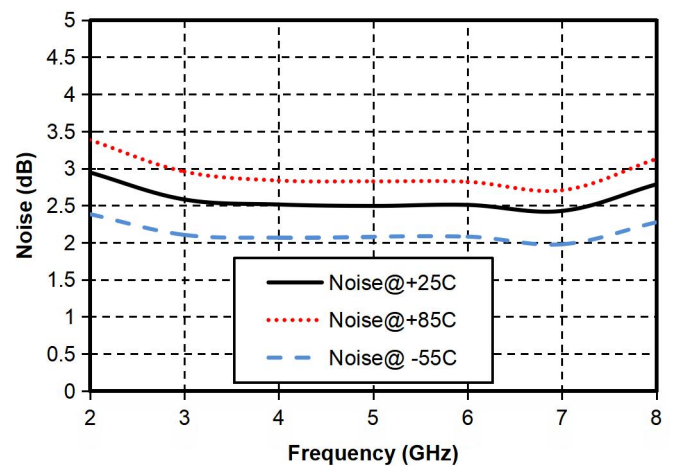
## GaAs MMIC Low Noise Amplifier Chip, 2-8 GHz

Main index test curve

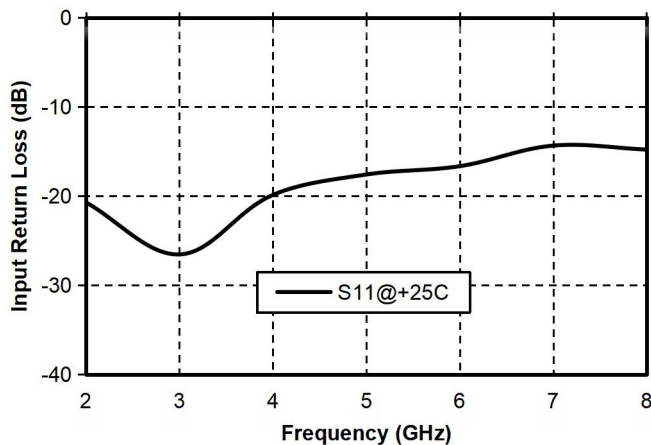
Gain vs. Temperature



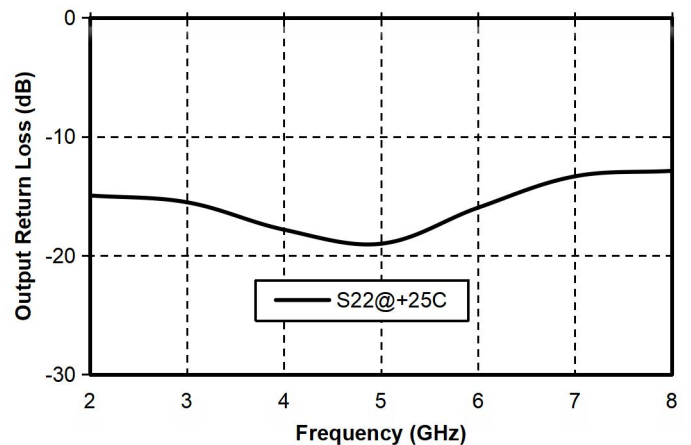
Noise Figure vs. Temperature



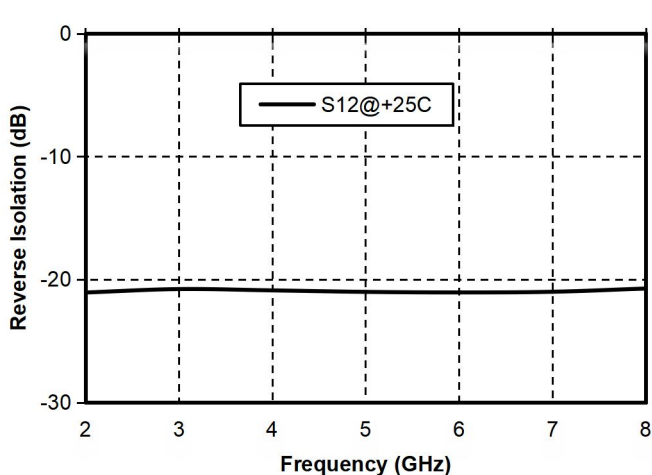
Input Return Loss vs. Frequency



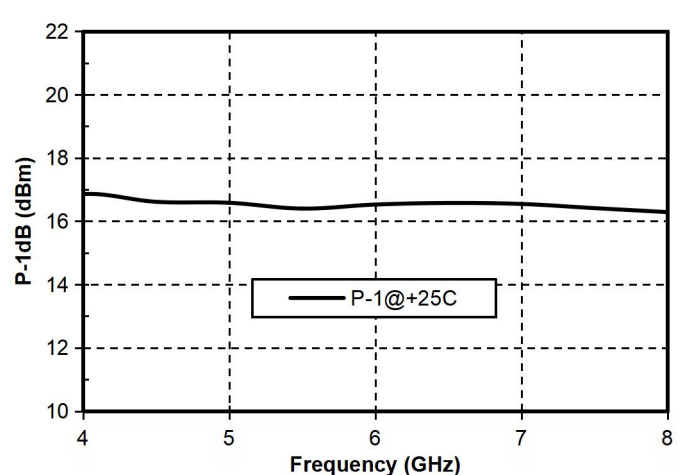
Output Return Loss vs. Frequency



Reverse Isolation vs. Frequency

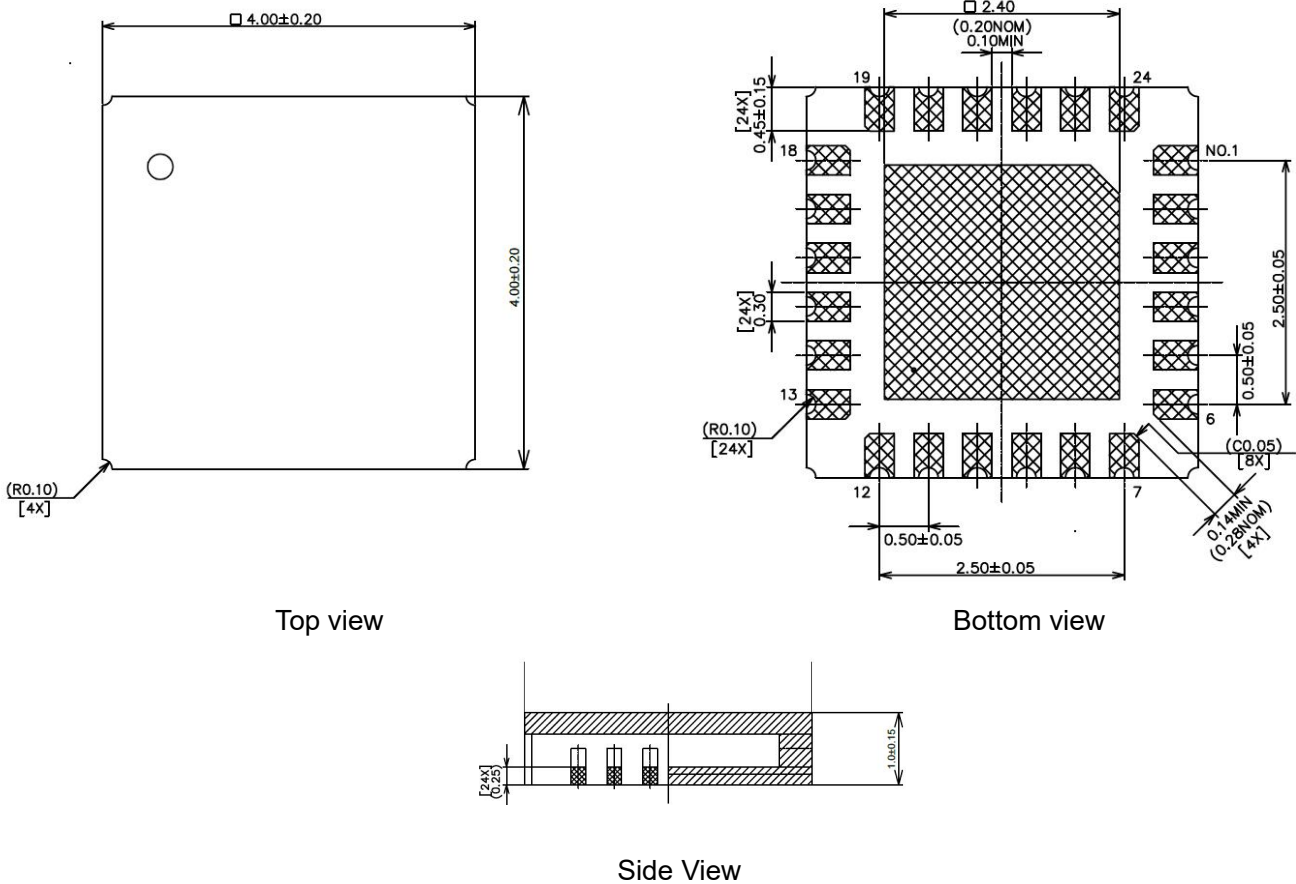


P-1dB vs. Temperature



## GaAs MMIC Low Noise Amplifier Chip, 2 - 8 GHz

### Appearance structure

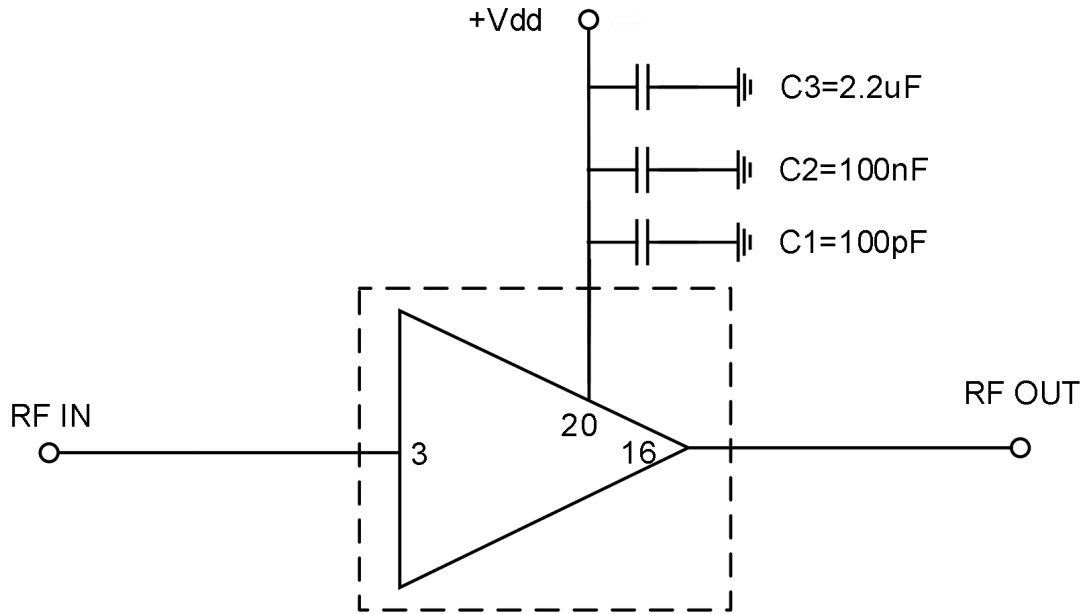


All units in the figures are millimeters .

Pin Definition		
Bonding point number	Function Symbol	Functional Description
3	RFIN	RF signal input terminal, no DC blocking capacitor required
16	RFOUT	RF signal output terminal, no DC blocking capacitor required
20	VDD	Amplifier Drain Bias
2, 4, 15, 17	GND	The bottom of the chip needs to be well grounded to RF and DC
1, 5~14, 18, 19, 21~24	NC	No welding required

## GaAs MMIC Low Noise Amplifier Chip, 2 - 8 GHz

### Recommended Circuit



Raw material	Capacitance, inductance, resistance
C1	100pF
C2	100nF
C3	2.2uF